

Noninjection Gram-Scale Synthesis of Monodisperse Pyramidal CuInS₂ Nanocrystals and Their Size-Dependent Properties

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Colloidal semiconductor nanocrystals (NCs) have shown great potential in applications as light-emitting and solar-harvesting materials since their optical properties can be tuned by size and shape due to quantum-confinement effects.^{1–3} For device applications, it is crucial that the nanocrystalline materials are of high quality, exhibiting narrow size and shape distributions, with a good colloidal stability, and a high crystallinity. To date numerous synthetic methodologies have been developed for the production of high quality cadmium- or lead-based NCs for biolabeling,⁴ lasers,⁵ light-emitting diodes,⁶ and solar cell applications.^{7–9} However, cadmium- or lead-based NCs have a doubtful future because of their high toxicity, and more recently researchers have turned their attention to ternary nontoxic I–III–VI compounds such as CuInS₂ and CuInSe₂ NCs.^{10–15}

Bulk CuInS₂ has a direct bandgap of 1.53 eV, which is well matched with the optimal spectral range for photovoltaic applications, resulting in CuInS₂ NCs having great potential as solar harvesters for a new generation of solution processed solar cells.^{16–20} Recent reports have demonstrated the potential of using CuInS₂ NCs in solar cell devices with power conversion efficiencies approaching ~5%.^{17–19} In addition, CuInS₂ NCs exhibit size tunable emission in the red to near-infrared (NIR) region (550–850 nm) for the NCs with diameters comparable to the exciton Bohr radius (~4.1 nm for CuInS₂). Furthermore, nano-

ABSTRACT CuInS₂ nanocrystals are viewed as very good candidates for solar harvesting and light emitting applications. Here we report an optimized noninjection method for the synthesis of monodisperse pyramidal CuInS₂ nanocrystals with sizes ranging from 3 to 8 nm. This synthetic route is able to yield large amounts of high quality nanoparticles, usually in the gram scale for one batch experiment. The structure and surface studies showed that the resulting nanocrystals are pyramids of CuInS₂ tetragonal phase with well-defined facets, while their surface is functionalized with dodecanethiol capping ligands. Spectroscopic and electrochemical measurements revealed size-dependent optical and electrical properties of CuInS₂ nanocrystals, demonstrating quantum confinement effects in these systems. The size-dependent optical bandgaps of CuInS₂ nanocrystals were found to be consistent with the finite-depth well effective mass approximation (EMA) calculations, which provide a convenient method to estimate the diameter of CuInS₂ pyramids. Additionally we have also determined some important physical parameters, including bandgaps and energy levels, for this system, which are crucial for the integration of CuInS₂ nanocrystals in potential device applications.

KEYWORDS: noninjection method · CuInS₂ nanocrystals · light emitters · solar harvesters · quantum confinement effects · energy levels · cyclic voltammetry

materials with light emission in this wavelength region are of importance in biolabeling and light-emitting diodes.^{2,4}

It is highly desirable that synthetic methods which are aimed at producing high quality nanomaterials for potential industrial applications are scalable, reproducible, environmentally friendly, and low cost, while enabling the production of nanocrystals in a high yield. Several synthetic methodologies for the production of CuInS₂ NCs at the multigram-scale have been explored, including the hot-injection method,^{15,21–25} hydrothermal techniques,^{26,27} chemical transformation route,²⁸ and thermal decomposition of suitable precursors.^{29–34} Since size, morphology, elemental stoichiometry, and crystal symmetry are known to

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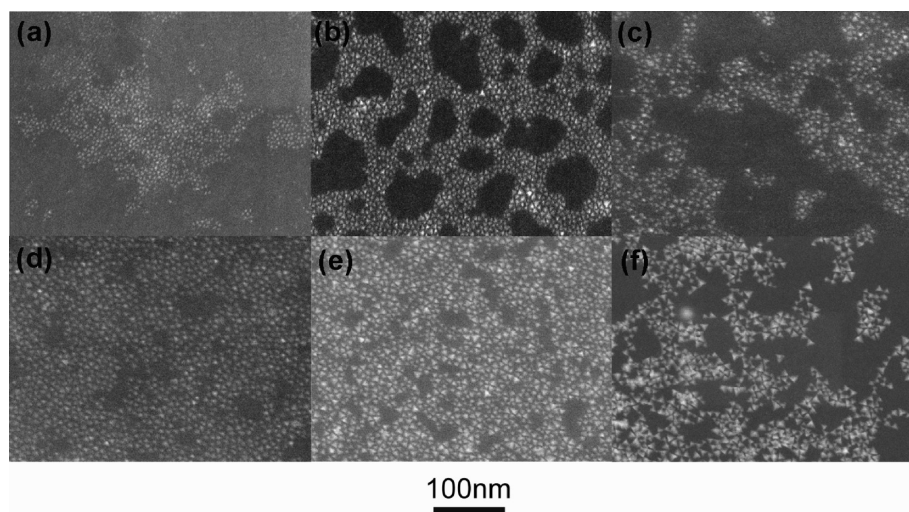


Figure 1. STEM images of CuInS₂ NCs with diameters of (a) 3.5 ± 0.4 , (b) 4.6 ± 0.6 , (c) 5.2 ± 0.7 , (d) 5.6 ± 0.7 , (e) 6.1 ± 1.1 , and (f) 7.3 ± 1.4 nm. These samples were prepared under identical synthetic conditions with varying reaction times of 20, 30, 45, 60, 90, and 120 min, respectively.

influence the properties of CuInS₂ NCs, it is of great interest to further explore the synthetic routes to achieve control and tunability of these vital parameters.

We recently developed a noninjection thermal decomposition route for the synthesis of CuInS₂ NCs with tunable absorption and emission spectra by heating inorganic metal salt and an alkanethiol complex.³⁵ A similar method has also been successfully employed by Li *et al.* in the synthesis of luminescent CuInS₂/ZnS NCs.³⁶ However, the resulting CuInS₂ NCs exhibited poor crystallinity and a large size distribution. In the current work, this synthetic method is further refined to give high quality monodisperse CuInS₂ NCs in a high yield. The as prepared CuInS₂ NCs have a pyramidal morphology and their diameters (determined by measuring the average edge lengths of pyramids, for a schematic diagram see Supporting Information Figure S1) can be easily tuned between ~ 3 and 8 nm by adjusting the reaction time. The chemical and physical characteristics of CuInS₂ NCs were investigated, including their size-dependent optical and electronic properties, which present some crucial parameters for the integration of these high quality materials in light emitting and solar harvesting applications.

RESULTS AND DISCUSSIONS

Synthetic Strategy. It has been known that the key to synthesizing monodisperse ternary NCs is to balance the reactivity of the two cationic precursors by their ligands, solvent matrix composition, and reaction temperature. Our previous work employed three components: indium acetate, copper acetate, and dodecanethiol.³⁵ CuAc, In(Ac)₃, and dodecanethiol initially react to form an intermediate complex. Upon heating, the complex acts as the precursor and decomposes into CuInS₂ particles, as the reaction time progresses. When the size of formed CuInS₂ nanoparticles exceeds 3 nm, the

nanoparticles are likely to aggregate and precipitate from the solution upon continuous heating. This could be attributed to the fast reaction between metal ions with dodecanethiol, which consumes the monomers quickly and results in the aggregation process. Taking that into consideration, the reaction system was modified as to decrease the reaction rate. (1) We use CuI to substitute for CuAc. According to the “hard–soft acid–base model”, Cu⁺ is a soft acid and Ac[−] is a hard base, whereas iodide and thiols (R-SH) are soft bases, where I[−] > HSR when the softness character is compared. Soft acid and soft base bind more tightly than soft base and hard acid pairs.³⁷ Therefore, the binding between I[−] with Cu⁺ is stronger than R-SH, slowing down the reactions between Cu⁺ and the S source (R-SH). (2) We also introduce oleic acid to decrease the reaction between indium ions with R-SH. (3) The reaction temperature was decreased to slow down the reactions.

In our previous synthesis, we have observed that the reaction system can produce some CuInS₂ NCs with nonspherical shapes by adding oleic acid.³⁵ Here, we also considered the synthetic chemistry to improve the uniformity of CuInS₂ NCs with nonspherical shapes. Inherently, nonspherical particles such as cubes and tetrahedral pyramids have a higher surface energy than spherical particles and require growth conditions characterized by a higher chemical potential.³⁸ In this CuInS₂ system, the higher chemical potential was achieved by increasing the concentration of reaction precursors.

Synthesis and Characterizations of CuInS₂ Pyramids. The reactions were systematically optimized, resulting in the successful synthesis of monodisperse CuInS₂ pyramids. The detail of material preparation can be seen in the Experimental Section. Figure 1 shows scanning transmission electron microscopy (STEM) images of NCs obtained after various reaction times ranging from 20 to

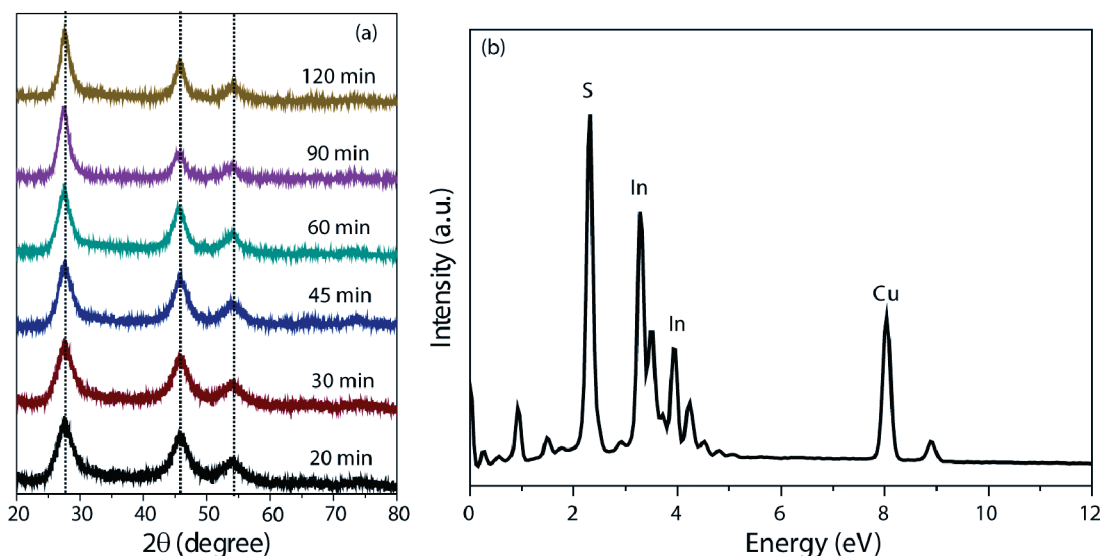


Figure 2. (a) XRD patterns of CuInS_2 NCs synthesized at different reaction times of 20, 30, 45, 60, 90, and 120 min. (b) A typical EDX spectrum of CuInS_2 NCs.

120 min. It was found that the resulting NCs exhibit pyramidal shapes. Their pyramidal shapes were further revealed in high magnification STEM images (see Supporting Information Figure S2). We determine their average diameters by measuring the average edge length of these pyramids. Detailed analysis indicates that these as-prepared NCs are nearly monodisperse, exhibiting diameters of 3.5 ± 0.4 , 4.6 ± 0.6 , 5.2 ± 0.7 , 5.6 ± 0.7 , 6.1 ± 1.1 , and 7.3 ± 1.4 nm for the samples synthesized at reaction times of 20, 30, 45, 60, 90, and 120 min, respectively. Compared to our previous report (2 to ~ 5 nm),³⁵ the size tunability of CuInS_2 NCs are greatly extended.

The structural phases of the NCs were determined through X-ray diffraction (XRD) characterizations. Figure 2 shows the XRD patterns of the CuInS_2 NCs obtained at different reaction times. Although the difference between chalcopyrite phase and zincblende phases is very small, the CuInS_2 NCs with zincblende phase usually have a diffraction peak of (200).^{23,31} In our work, the absent of this peak in the XRD patterns of CuInS_2 NCs can be an indirect evidence for the chalcopyrite phase. In addition, subsequent HRTEM results implied a chalcopyrite phase. Therefore, the XRD patterns were tentatively identified to reported chalcopyrite phase.³⁵ The first three diffraction peaks can be indexed to the (112), (204)/(220), and (116)/(312) reflections of the tetragonal crystal structure. In addition, XRD characterizations can also be used to determine the size evolution of NCs as a function of time by applying the Scherrer equation:

$$D_{\text{eff}} = K\lambda/B \cos(\theta_B) \quad (1)$$

where D_{eff} is the effective diameter determined by XRD, K is the Scherrer constant related to the shape of crystallites. λ is the X-ray wavelength, B is the full width at half-maximum of the diffraction peak, and θ_B is the half

angle of the diffraction peak on the 2θ scale. Since the (112) plane of tetragonal phase equals to the (111) plane in cubic phase, we choose the Scherrer constant of 0.89 for tetrahedral crystallites perpendicular to the (111) plane in this calculation.³⁹

The utility of the Scherrer equation for determination of the nanocrystal size in monodisperse systems has been demonstrated in detail in previous reports.^{40–42} Since the broadening of Bragg reflections is determined by the number of unit cells along columns perpendicular to the diffraction planes, calculation of the particle size with the Scherrer equation usually leads to an effective diameter, D_{eff} which is usually smaller than the geometric diameter (d) (see Supporting Information Figure S3). Here we use $d = \frac{3}{2}D_{\text{eff}}$ to estimate the mean geometric diameter (d_{XRD}) of CuInS_2 NCs from the (112) peaks (shown in Table 1), and we find these values to be in very good agreement with the results from STEM analysis. This shows that the properly adapted Scherrer equation is suitable for the determination of the size of the resulting pyramidal CuInS_2 NCs.

To obtain information about the chemical composition, energy dispersive X-ray (EDX) spectra and inductively coupled plasma atomic emission (ICP-AES) measurements were performed. A typical EDX spectrum is shown in Figure 2b, which confirmed the existence of Cu, In, and S elements in the as synthesized NCs. The elemental compositions of as prepared NCs were also determined by EDX and ICP–AES measurements (see Table 1). Temporal evolution of EDX measurements revealed that the evolving NCs are copper-rich (Cu:In composition of 1.71:1) in the early stage of the reaction. Then there is a continuous decrease of Cu with reaction time, resulting in a more stoichiometric composition (Cu:In composition of 1.03:1 and 0.94:1 for the resulting NCs obtained at 90 and 120 min, respectively)

TABLE 1. The Average Diameters and Elements Compositions of As-Prepared CuInS₂ NCs Determined by Corresponding Measurements

samples	S1 (20 min)	S2 (30 min)	S3 (45 min)	S4 (60 min)	S5 (90 min)	S6 (120 min)
$\langle d_{\text{XRD}} \rangle$ (nm)	3.6	4.0	5.1	5.5	6.1	7.6
$\langle d_{\text{STEM}} \rangle$ (nm)	3.5	4.6	5.2	5.6	6.1	7.3
Cu/In/S from EDX	1.71:1:2.1	1.56:1:2.2	1.36:1:1.8	1.21:1:1.83	1.03:1:1.9	0.92:1:1.91
Cu/In from ICP–AES	2.4:1	2.0:1	1.8:1	1.8:1	1.71:1	1.15:1

in the final stage. These results demonstrate that the Cu/In ratio in resulting CuInS₂ NCs shows a size-dependence. It is possible that the higher binding ability and reactivity of copper with dodecanethiol comparable to indium results in Cu-rich NCs during the initial growth stage, which is later recovered by reactivity of excess indium.

We further revealed the crystalline nature of the NCs by using high-resolution transmission electron microscopy (HRTEM) experiments (see Figure 3). The crystal quality was evidenced by the continuous lattice fringes and very clear crystal facets. On the basis of the HRTEM analysis, the observed lattice fringes with a distance of 0.320 nm can be identified to the (111) plane of the zincblende phase or the (112) plane of the chalcopyrite phase. If the CuInS₂ pyramids are of zincblende phase, then the four facets should be (111) face,^{43,44} which is not consistent with the observation of the lattice fringes with a distance of 0.320 nm. Therefore, the CuInS₂ pyramids are of the chalcopyrite phase and the lattice fringes with a distance of 0.320 and 0.195 nm correspond to the (112) and (220) planes of the CuInS₂ chalcopyrite phase.¹⁵ These results are similar to the observations in CuInSe₂ pyramids by Korgel *et al.*⁴⁵ The formation of pyramidal shapes can also be explained by using the “surface-facet polarity models”. The CuInS₂ chalcopyrite structure is derived from the II–VI zincblende structure by substituting group I and group III Cu and In atoms for the group II atoms. The (112) plane of the CuInS₂ tetragonal phase, equivalent to the (111) plane of the zinc-blende phase, is a polar surface, which

is likely an anion- or cation-terminated surface. These polar surfaces have a higher surface energy and are very reactive. The fast growth along the [112] direction normally results in the diminishing of the (112) plane, leaving nonpolar surfaces such as (114) planes.

Surface Properties. Because of their small dimensions, NCs have an inherently large surface to volume ratio, and it has been shown in a number of systems and potential applications that surface properties play a crucial role.^{7,46} As such, it is important to investigate the functionalization of the surface, determining the extent of surface coverage and the nature of the capping ligands, that tend to associate with surface atoms and surface defects. In this CuInS₂ system, we have introduced two surfactants in the synthetic method, allowing for the possibilities of dodecanethiol coverage, oleic acid coverage, or a presence of both ligands (dodecanethiol + oleic acid) on the surface of CuInS₂ nanocrystals. Figure 4a shows the Fourier transform infrared spectra (FTIR) spectra of resulting NCs in comparison with pure ligands (also see Supporting Information Figure S4). The absence of the C=O vibration mode around 1550–1700 cm⁻¹ indicates that the final nanocrystalline CuInS₂ product contains no oleic acid on the NC surface.

Optical Properties. It has been known that the optical properties of ternary NCs depend on their size, shape, composition, and surface states.^{21,35} The UV–vis absorption spectra of the as-prepared CuInS₂ NCs have been measured at room temperature and are shown in Figure 5a. For all samples, a broad absorption band

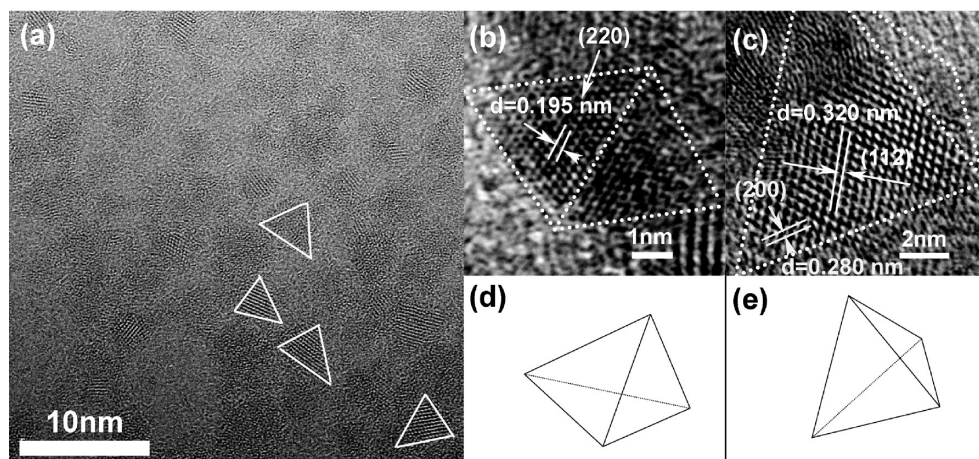


Figure 3. (a) HRTEM images of CuInS₂ NCs with an average diameter of 5.2 nm; (b, c) two representative HRTEM images of a single CuInS₂ NC; (d, e) schematic diagrams corresponding to CuInS₂ pyramids in b and c, respectively.

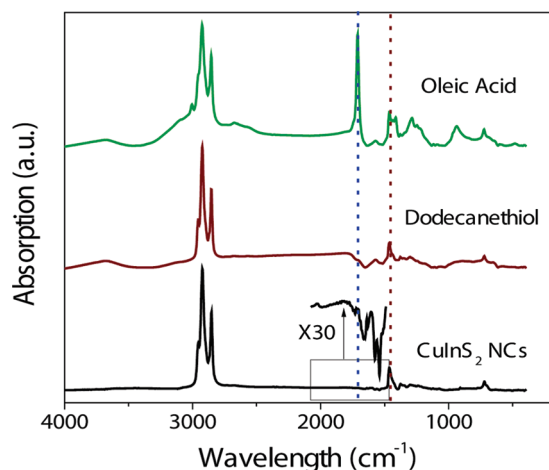


Figure 4. (a) FTIR spectrum of as synthesized CuInS_2 NCs in comparison to spectra of oleic acid and dodecanethiol.

is observed together with an absorption tail at longer wavelengths. As the NCs become larger, the absorption edge gradually shifts toward longer wavelengths. Similar to previous observations, no sharp absorption peak was observed for any of the samples.^{21,35} The absorption coefficient of semiconductor materials is related to the density of excited states that are generated through the absorption of photons with corresponding energy. For semiconductors with direct bandgaps, it is possible to estimate the lowest excited states by the following empirical formula:⁴⁷

$$\alpha_{h\nu} = \sqrt{(h\nu - E_x)} \quad (2)$$

where α is the absorption coefficient, ν is the light frequency, h is Planck's constant ($h\nu$ is the energy of a photon with frequency ν), and E_x is the optical band gap energy.

Since the CuInS_2 nanocrystals did not possess excitonic peaks, we adapted eq 2 by plotting α^2 versus $h\nu$,

TABLE 2. Comparison of the Bandgaps of CuInS_2 NCs Determined by Absorption Spectra and Cyclic Voltammetry Measurements^a

average sizes	3.5 nm	5.2 nm	5.6 nm	6.1 nm	7.3 nm
E_g (determined by CV) (eV)	2.04	1.88	1.80	1.78	1.70
E_x (determined by absorption) (eV)	1.945	1.798	1.757	1.719	1.668
E_b (binding energy) (meV)	~95	~82	~43	~61	~32

^aThe binding energies of CuInS_2 NCs with different sizes were calculated by following the equation $E_b = E_g - E_x$. Note: the exciton binding energy has at least an error bar of ~25 meV from the cyclic voltammetry measurements.

which forms a straight line and allows us to measure the optical bandgaps of CuInS_2 NCs of various sizes (see Supporting Information Figure S5). Since the CuInS_2 NCs are nearly monodisperse, it is acceptable to measure their direct bandgap by extrapolating a straight line to the $\alpha = 0$ axis in the plots of α^2 versus $h\nu$. In this way, the lowest excited states, thus the optical bandgaps of CuInS_2 NCs were determined. The results are listed in Table 2.

The photoluminescence (PL) spectra of CuInS_2 pyramids were also measured (see Supporting Information Figure S6). Similar to previous reports, the CuInS_2 NCs have a very broad PL emission.^{21,35} It was observed that the PL emission gradually shifted to the longer wavelength in the range of NIR region (700 to ~900 nm) with the diameter increasing. Two-dimensional photoluminescence excitation (2D PLE) spectroscopy, obtained by measuring PL spectra over a range of excitation energies, contains information of PLE and PL spectra.⁴⁸ Figure 5b shows a typical 2D PLE spectrum of CuInS_2 pyramids. An obvious gap between excitation and emission due to the Stokes shift was observed. Compared to absorption spectra, the feature illustrating the optical band in PLE spectra is more easily identified. By drawing a vertical PLE line in the emission peak and inclined size distribution emission line along the PLE peak, we

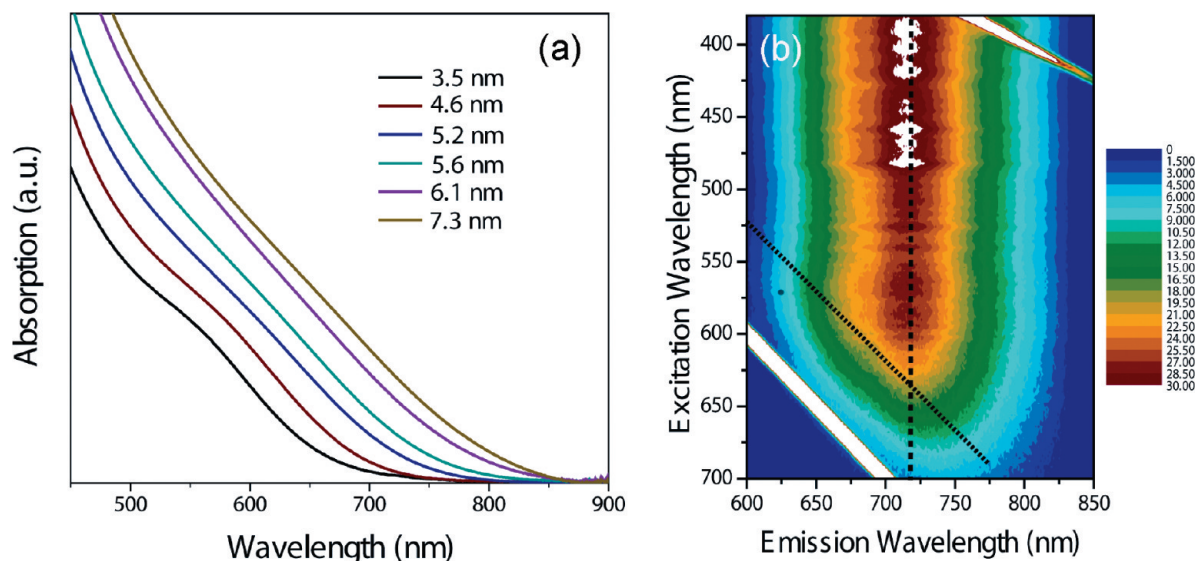


Figure 5. (a) Absorption spectra of CuInS_2 NCs with different average size of 3.5, 4.6, 5.3, 5.6, 6.1 and 7.3 nm; (b) 2D PLE spectra of CuInS_2 NCs with average diameter of 3.5 nm. The PL intensity was represented by colors.

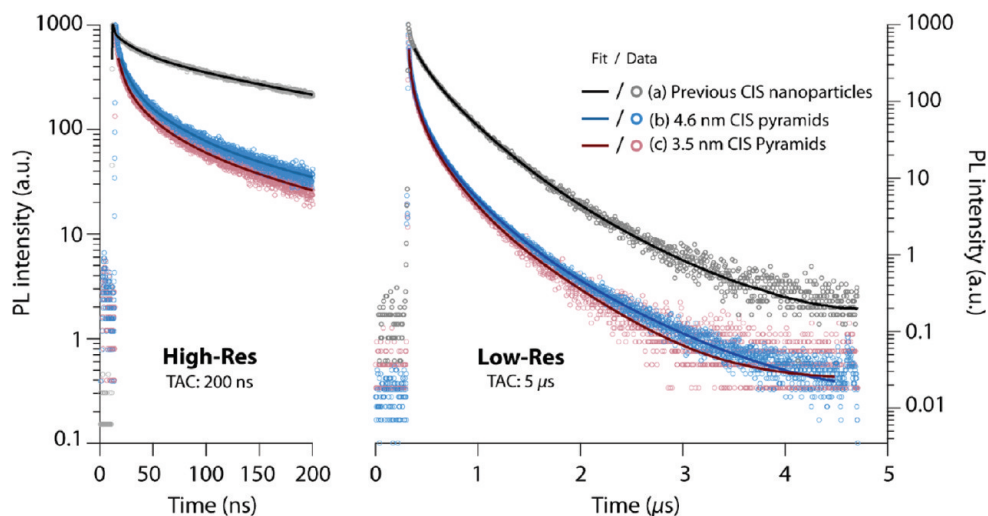


Figure 6. PL decay of CuInS_2 samples: (a) CuInS_2 nanoparticles with average diameters of 2.6 nm prepared by using previous method,³⁵ (b and c) CuInS_2 pyramids with average diameters of 4.6 and 3.5 nm.

find that the y -value of the intercept corresponds to the energy of the band edge exciton states, which provides the parameter of optical bandgap energies.

PL dynamics contains information about radiative and nonradiative relaxation processes. Recent research from our group has established how time-resolved PL can be used as a quantitative tool for the analysis of photoexcitation dynamics in colloidal semiconductor nanocrystals.^{49,50} Long time scale decay components in the PL emission of NCs are often related to intrinsic defects and surface defects.^{34–36} The time-resolved PL of a sample of NCs directly reflects the transient population that is distributed in radiative core states and indirectly indicate participation in the nonradiative relaxation process of surface-related trap states.

The time-resolved PL spectra of CuInS_2 NCs at their emission peak are shown in Figure 6. The PL decays are multiexponential, which likely indicates decayed PL resulting from surface traps. Such nonexponential decays are often quantified using an average PL lifetime, which is the average time, after the excitation pulse, at which an emitted photon is detected. The data was analyzed by least-squares iterative reconvolution of a model multiexponential function with an experimental instrument response function. The average lifetime was then calculated using

$$\tau_{\text{avg}} = \frac{\sum_n \alpha_n \tau_n^2}{\sum_n \alpha_n \tau_n} \quad (3)$$

where $1/\tau_n$ is the decay constant of component n in the model multiexponential function.

It was found that the average PL lifetimes were reduced from ~ 300 ns for the CuInS_2 nanoparticles synthesized by the previous method³⁵ to 140–160 ns for the high quality CuInS_2 pyramids obtained in this work. The decrease of average PL lifetime in CuInS_2 pyramids

can be attributed to the reduction of surface-related trap states.^{49,51} Because of the high crystallinity and the faceted structure of these newly prepared CuInS_2 pyramids whose surface is well protected by capping ligands, it would be reasonable to conclude that the density of nonradiative surface traps is lower in these high quality CuInS_2 NCs.

Quantum Confinement Effects. The basic quantum confinement effects in NCs have been of great fundamental interest because it provides tunability of optical properties.⁵² The quantum confinement effects in nonspherical NCs are of particular interest for their potential shape-tuning effects.⁵³ On the basis of the investigation of bulk film, it was determined that the chemical composition has limited influence on the optical bandgaps of CuInS_2 materials.^{54,55} The obvious blue shift in absorption spectra should be related to quantum confinement effects. The size-dependent optical bandgap is a direct way to demonstrate the quantum confinement effects in NCs. For CuInS_2 NCs we plot the size-dependent optical bandgap determined from absorption and 2D PLE spectra in Figure 7. Models based on the effective mass approximation (EMA) are often used to describe the energy levels in semiconductor NCs.⁵⁶ Recently, Omata *et al.* have evaluated size dependent bandgaps of I–III–VI NCs by using the finite-depth-well EMA calculation.⁵⁷ On the basis of their calculations, the optical bandgap of I–III–VI NCs can be described by the following empirical relation:

$$x \cot(x) = 1 - \left(\frac{m^*}{m_0}\right) - \sqrt{\left(\frac{m^*}{m_0}\right) \left(\frac{V_0}{\Delta} - x^2\right)} \quad (4)$$

where $V_0 = (E_{\text{gcap}} - E_{\text{gbulk}})/2$, $x = (\sqrt{2m^*E_{\text{r0}}^2/\hbar^2})^{1/2}$, E_{gcap} is the energy gap between the LUMO and the HOMO of the capping surfactant, E_{gbulk} is the energy band gap of the bulk semiconductor and r_0 is the radius of the nanoparticles. When the confinement potential is finite, there is no analytical solution of the eigenvalue equa-

tion and, hence, eq 4 is numerically solved by substituting $m^* = m_e^*$ for the electrons and $m^* = m_h^*$ for the holes. Dodecanethiol is the organic capping ligand on the CuInS₂ NC surface. E_{gcap} of dodecanethiol has been experimentally determined to be ~ 7 eV.⁵⁸ So, $E_{\text{gcap}} = 7$ eV, $m_e^*/m_0 = 0.16$, $m_h^*/m_0 = 1.3$, and $E_{\text{gbulk}} = 1.53$ eV were used for the calculation, which is represented by the black line in Figure 7. There is a very good correspondence between experimental results and the finite depth-well EMA predictions, indicating that the diameter of CuInS₂ NCs can be estimated by comparison of the optical bandgap with the finite-depth-well EMA calculation results.

Electrochemical Properties. Considering the application of NCs in electroluminescence and solar cell devices, the bandgaps and energy levels are vital parameters for devices design and material selections.^{6,59} Cyclic voltammetry (CV) has been proven to be an effective method for the determination of bandgaps as well as the energy levels of the highest occupied molecular orbital (HOMO) and the lowest unoccupied molecular orbital (LUMO) of conjugated polymers and organic molecules.⁶⁰ This method has been successfully adapted to measure the energy levels in semiconductor NCs,^{61–65} although interpretation of these data by surface states can be complicated. The oxidation process is related to the injection of a hole into the HOMO level, and the reduction process is related to the injection of an electron into the LUMO level. The energy levels (HOMO and LUMO) can be calculated from the onset oxidation potential (E^{ox}) and onset reduction potential (E^{red}), respectively, according to the following equations:

$$E_{\text{HOMO}} = -I_p = -(E^{\text{ox}} + 4.71) \text{ eV} \quad (5)$$

$$E_{\text{LUMO}} = -E_a = -(E^{\text{red}} + 4.71) \text{ eV} \quad (6)$$

where the unit of the potentials is V vs Ag/Ag⁺ (0.01 M) reference electrode.

CV curves of CuInS₂ NCs with different average sizes deposited on a carbon electrode were measured and the results are shown in Figure 8a (a typical CV curve of a blank was shown in the Supporting Information Figure S7). According to the literature,⁶⁶ the bulk bandgap of CuInS₂ is 1.53 eV and their HOMO and LUMO levels are *ca.* -5.6 and -4.1 eV, respectively (these values correspond to oxidation and reduction potentials of *ca.* 0.9 and -0.6 V). Distinct peaks with potential higher than 0.9 V in the oxidation process or lower than -0.6 V in reduction processes are related to the injection of holes to the HOMO levels or electrons to the LUMO levels.²⁵ The onset of oxidation and reduction peaks were identified and labeled by dotted lines in Figure 8a. The corresponding bandgap values and energy levels of these samples were calculated (according to eqs 5 and 6) and shown in Table 2 and Figure 8b (see Supporting Information Table S8). The CV results can also be used

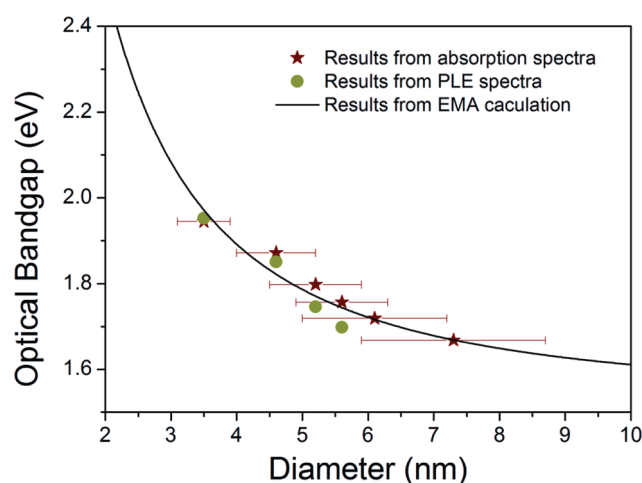


Figure 7. Size-dependent optical bandgaps of CuInS₂ NCs determined from absorption (red stars) and 2D PLE spectra (green spheres) illustrating quantum confinement. The solid line represents the calculation result from finite depth-well EMA theory.⁵⁷

to estimate the size-dependent quantum confinement in CuInS₂ NCs. Figure 8b shows the energy levels of CuInS₂ NCs with different average size comparing them to bulk values. The decrease of the energy of the HOMO levels and the corresponding increase in energy of the LUMO levels are in good agreement with the theoretical expectations.

CV measurements determined the values of lowest conductive states and highest valence states, corresponding to the electronic bandgap (E_b). The spectroscopic measurements give the optical band (E_x), which corresponds to the value of the electronic bandgap (E_g) minus the exciton binding energy (E_b). Thus, the exciton binding energy (E_b) can be defined as $E_b = E_g - E_x$. We calculated the exciton binding energy by using our CV and spectroscopic experimental results. The exciton binding energy in CuInS₂ NCs is found to be in the range of 100–30 meV and shows a decreasing trend with increasing NC diameter, corresponding to the size-dependence of the electron–hole Coulomb interaction. This observation also provides evidence that photoexcitation of CuInS₂ NCs generates excitons.

CONCLUSIONS

We have further developed the noninjection method for the synthesis of monodisperse pyramidal CuInS₂ NCs, whose size can be tuned from 3 to 8 nm. STEM, XRD, and HRTEM characterizations show that fabricated NCs are of high quality. EDS and ICP–AES show that the resulting NCs are copper-rich for the smaller dots and become stoichiometric for the larger ones. This newly developed synthetic methodology is ideal in a number of ways as it can be easily altered to yield a high quality product on a gram scale, is highly reproducible, and is based on green chemistry. The scalability of the reaction is vital as the development of potential applications, where high quality CuInS₂ NCs could

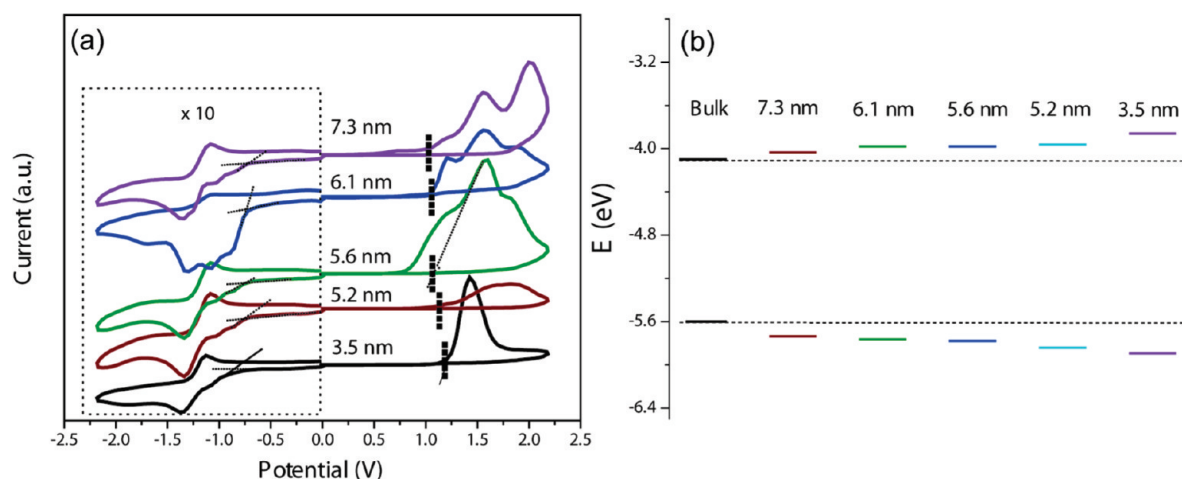


Figure 8. (a) Cyclic voltammograms of CuInS_2 nanocrystals with average diameters of 3.5, 5.2, 5.6, 6.1, and 7.3 nm; (b) the energy levels of CuInS_2 nanocrystals with different average diameters determined by cyclic voltammetry.

be integrated as light emitters and solar harvesters, would require the production of these nanomaterials at a much larger scale. To investigate the potential of the integratability of CuInS_2 NCs into electronic devices, we have carefully studied the surface-, optical-, and electrochemical properties of resulting NCs. The FTIR results have indicated that the surface of synthesized CuInS_2 NCs is functionalized with dodecanethiol capping ligands. Size-dependent bandgaps and energy levels were determined through spectroscopic and CV measurements, illustrating the presence of quantum confinement effects in this system. By comparing the bandgaps determined by CV measurements and the

optical bandgaps from the spectroscopic measurements, the exciton binding energy of CuInS_2 pyramids was resolved. This provides evidence that the light absorbed by CuInS_2 NCs mainly generates photoexcited excitons. Vital parameters obtained through these experimental results can be very helpful in the design and development of high performance CuInS_2 NC based electronic devices. Future work will focus on the exploration of these high quality NCs for light emitting and solar harvesting applications. In addition, this method can also be simply extended to $\text{Zn}_x(\text{CuIn})_{1-x}\text{S}_2$ and $\text{CuGa}_x\text{In}_{1-x}\text{S}_2$ systems, which are also of interest for light emitting and solar harvesting applications.

EXPERIMENTAL SECTION

Chemicals. Copper(I) iodide (Fluka, $\geq 98\%$), copper(I) acetate (Strem Chemicals, 99%), indium(III) acetate (Aldrich, 99.999%), *n*-dodecanethiol (Aldrich, $\geq 98\%$), oleic acid (OA, Aldrich, 90%), and 1-octadecene (ODE, Aldrich, 90%) were used as purchased and without further purification.

Synthesis of Pyramidal CuInS_2 NCs. In a typical synthesis CuI (0.191 g, 1 mmol) and $\text{In}(\text{Ac})_3$ (0.292 g, 1 mmol) were mixed with 1 mL of dodecanethiol in a 50 mL three-necked flask, which was followed by the addition of 10 mL of ODE. The mixture was then degassed at 120 °C. After 30 min, 1 mL of oleic acid was added into the reaction flask, and the solution was continuously degassed for another 30 min. After that, the solution was heated to 200 °C under argon flow and kept for a fixed time (20, 30, 45, 60, 90, 120 min). During the reaction, aliquots were taken with a syringe at different times to monitor the growth of CuInS_2 NCs by recording UV–vis and PL spectra (7, 20, 30, 45, 60, 90, 120 min). Afterward, the reaction solution was cooled to room temperature and precipitated by acetone. The flocculent precipitate that formed was centrifuged, while the supernatant liquid was decanted, and the isolated solid was dispersed in toluene or chloroform. The above centrifugation and isolation procedure was then repeated several times for purification of the prepared CuInS_2 NCs. Finally, the products were redispersed in toluene or chloroform or dried under vacuum for further analyses.

Gram-scale synthesis of the CuInS_2 NCs was performed by heating a mixture of 1.91 g of CuI , 2.92 g of $\text{In}(\text{Ac})_3$, 10 mL of dodecanethiol, 10 mL of oleic acid, and 100 mL of ODE in a 500 mL three-necked flask at 200 °C for 2 h. The product yield was 80%–90% (~2.3 g of CuInS_2 NCs) (see Supporting Information Figure S1).

Characterizations. STEM images were acquired using a Hitachi HD-2000 instrument equipped at 200 kV. EDX spectra was performed on a Hitachi 5200 instrument equipped with an Oxford Instruments Inca EDX system operated at 20 kV. HRTEM images were recorded using a JEOL-2100F instrument equipped with a Gatan camera operated at 200 kV. XRD measurements were carried out on a Siemens D5000 diffractometer using a high-power $\text{Cu K}\alpha$ source operating at 50 kV and 35 mA with a Kevex solid-state detector. A step scan mode was used for data collection with a step size of 0.028 and time of 2.0 s per step. ICP–AES measurements were performed as follows. Purified CuInS_2 NC samples were dried by gentle heating under argon, and then the sample was digested by 0.5 mL of aqua regia. The digested sample was transferred into a volumetric flask to make a fixed volume aqueous solution for the ICP–AES measurements. Absorption spectra and steady PL spectra were obtained on a CARY 100 BIO UV–vis spectrophotometer and CARY Varian fluorescence spectrometer, respectively. FTIR spectra in the region of 400–4000 cm^{-1} were recorded on a BRUKER TENSOR 27 with 4 cm^{-1} resolution. Photoluminescence decays were measured by time-resolved single photon counting using an IBH DataStation Hub system coupled to an IBH 5000 M monochromator and a R3809U-50 cooled MCP PMT detector. The samples were excited at 450 nm using a Ti:sapphire Tsunami laser model 3950 ps with a GWU-23PL multiharmonic generator, both from Spectra-Physics. Cyclic voltammograms (CVs) were recorded on a Zahner IM6e electrochemical workstation, using glassy carbon discs as the working electrode ($\sim 0.25 \text{ cm}^2$), a Pt wire as the counter-electrode, and Ag/Ag^+ (Ag wires with 0.01 M AgNO_3 in acetonitrile) as the reference electrode; 0.1 M tetrabutylammoniumhexafluorophosphate (TBAPF_6) dissolved in acetonitrile was

employed as the supporting electrolyte. All NC samples were purified and redissolved in chloroform. The working electrodes were polished, cleaned, and dried before depositing the NC samples. A drop of diluted NC solution was deposited onto the surface of the working electrode to form a NC film. The scan rate was set at 50 mV/s, and during all the experiments, the electrolyte solutions were thoroughly deoxygenated by bubbling high purity nitrogen for 15 min. A nitrogen atmosphere was maintained over the solution.

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Supporting Information Available: The high magnification STEM images, illustration of diameter determination, illustration of shape treatment of Scherrer equation, plots of absorption coefficient and photon energy, additional FTIR spectra, CV blank and parameters of CV results. This material is available free of charge via the Internet at <http://pubs.acs.org>.

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